

S-576B B Series

Applications

125°C OPERATION. HIGH-WITHSTAND VOLTAGE, HIGH-SPEED, **BIPOLAR HALL EFFECT LATCH IC**

www.ablic.com

Rev.1.4 00

© ABLIC Inc., 2019-2022

This IC, developed by CMOS technology, is a high-accuracy Hall effect latch IC that operates with high temperature and high-withstand voltage.

The output voltage level changes when this IC detects the intensity level of magnetic flux density and a polarity change. Using this IC with a magnet makes it possible to detect the rotation status in various devices.

ABLIC Inc. offers a "magnetic simulation service" that provides the ideal combination of magnets and our Hall effect ICs for customer systems. Our magnetic simulation service will reduce prototype production, development period and development costs. In addition, it will contribute to optimization of parts to realize high cost performance. For more information regarding our magnetic simulation service, contact our sales representatives.

Features

- Uses a thin (t0.80 mm max.) TSOT-23-3S or ultra-thin (t0.50 mm max.) HSNT-6(2025) package, allowing for device miniaturization
- · Contributes to reduction of mechanism operation dispersion with high-accuracy magnetic characteristics (Typ. value ± 1.0 mT) (Refer to "■ Magnetic Characteristics" for details.)
- · Contributes to device safe design with a built-in output current limit circuit

Specifications

Pole detection:	Bipolar latch	DC brushless motor
• Output logic*1:	V _{OUT} = "L" at S pole detection V _{OUT} = "H" at S pole detection	Power toolHome appliance
• Output form ^{*1} :	Nch open-drain output Nch driver + built-in pull-up resistor (1.2 k Ω typ.)	 Housing equipment Industrial equipment
 Magnetic sensitivity^{*1}: 	$B_{OP} = 0.5 \text{ mT typ.}$ $B_{OP} = 2.2 \text{ mT typ.}$	
	$B_{OP} = 3.0 \text{ mT typ.}$ $B_{OP} = 6.0 \text{ mT typ.}$	Packages
	$B_{OP} = 10.0 \text{ mT typ.}$	• TSOT-23-3S
Chopping frequency: Output delay time:	$f_{C} = 500 \text{ kHz typ.}$ $t_{D} = 8.0 \mu \text{s typ.}$	• HSNT-6(2025)
 Power supply voltage range^{*2}: 	V _{DD} = 2.7 V to 26.0 V	

Built-in regulator

• Built-in output current limit circuit

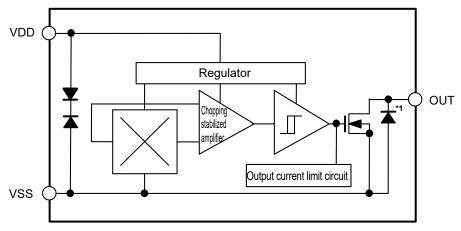
- Operation temperature range: $Ta = -40^{\circ}C \text{ to } +125^{\circ}C$
- Lead-free (Sn 100%), halogen-free

*1. The option can be selected.

*2. V_{DD} = 2.7 V to 5.5 V when output form is Nch driver + built-in pull-up resistor (1.2 k Ω typ.)

Block Diagram

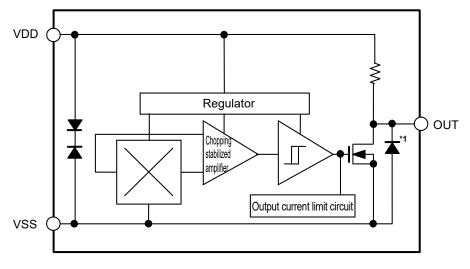
1. Nch open-drain output product



*1. Parasitic diode



2. Nch driver + built-in pull-up resistor product

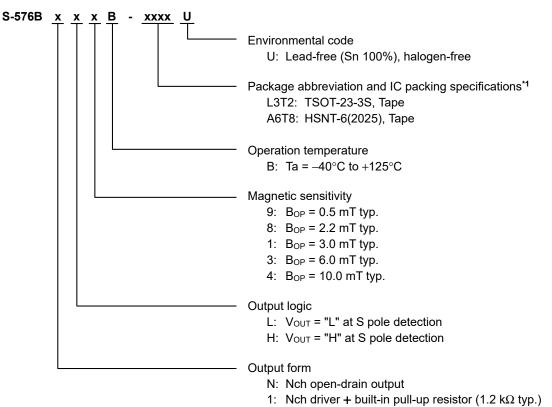


*1. Parasitic diode

Figure 2

Product Name Structure

1. Product name



*1. Refer to the tape drawing.

2. Packages

 Table 1
 Package Drawing Codes

Package Name	Dimension	Таре	Reel	Land	Stencil Opening
TSOT-23-3S	MP003-E-P-SD	MP003-E-C-SD	MP003-E-R-SD	_	_
HSNT-6(2025)	PJ006-B-P-SD	PJ006-B-C-SD	PJ006-B-R-SD	PJ006-B-LM-SD	PJ006-B-LM-SD

3. Product name list

3.1 TSOT-23-3S

Table 2									
Product Name	Output Form	Power Supply Voltage Range	Output Logic	Magnetic Sensitivity (Bop)					
S-576BNH9B-L3T2U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "H" at S pole detection	0.5 mT typ.					
S-576BNL9B-L3T2U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "L" at S pole detection	0.5 mT typ.					
S-576BNL8B-L3T2U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "L" at S pole detection	2.2 mT typ.					
S-576BNH1B-L3T2U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "H" at S pole detection	3.0 mT typ.					
S-576BNL1B-L3T2U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "L" at S pole detection	3.0 mT typ.					
S-576BNL3B-L3T2U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "L" at S pole detection	6.0 mT typ.					
S-576B1L8B-L3T2U	Nch driver + built-in pull-up resistor (1.2 k Ω typ.)	V _{DD} = 2.7 V to 5.5 V	V _{OUT} = "L" at S pole detection	2.2 mT typ.					
S-576B1L1B-L3T2U	Nch driver + built-in pull-up resistor (1.2 k Ω typ.)	V _{DD} = 2.7 V to 5.5 V	V _{OUT} = "L" at S pole detection	3.0 mT typ.					

Remark Please contact our sales representatives for products other than the above.

3.2 HSNT-6(2025)

Table 3

Product Name	Output Form	Power Supply Voltage Range	Output Logic	Magnetic Sensitivity (B _{OP})
S-576BNL9B-A6T8U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "L" at S pole detection	0.5 mT typ.
S-576BNL8B-A6T8U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "L" at S pole detection	2.2 mT typ.
S-576BNL1B-A6T8U	Nch open-drain output	V _{DD} = 2.7 V to 26.0 V	V _{OUT} = "L" at S pole detection	3.0 mT typ.
S-576B1L8B-A6T8U	Nch driver + built-in pull-up resistor (1.2 kΩ typ.)	V _{DD} = 2.7 V to 5.5 V	V _{OUT} = "L" at S pole detection	2.2 mT typ.
S-576B1L1B-A6T8U	Nch driver + built-in pull-up resistor (1.2 k Ω typ.)	V _{DD} = 2.7 V to 5.5 V	V _{OUT} = "L" at S pole detection	3.0 mT typ.

Remark Please contact our sales representatives for products other than the above.

Pin Configurations

1. TSOT-23-3S

Top view



Pin No.	Symbol	Description							
1	VSS	GND pin							
2	VDD	Power supply pin							
3	OUT	Output pin							

Table 4

Figure 3

2. HSNT-6(2025)



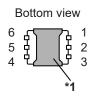


	Table 5									
Pin No.	Symbol	Description								
1	VDD	Power supply pin								
2	NC*2	No connection								
3	OUT	Output pin								
4	NC*2	No connection								
5	VSS	GND pin								
6	NC*2	No connection								

- Figure 4
- *1. Connect the heatsink of backside at shadowed area to the board, and set electric potential open or GND. However, do not use it as the function of electrode.

*2. The NC pin is electrically open.

The NC pin can be connected to the VDD pin or the VSS pin.

Absolute Maximum Ratings

Table 6									
	ltem	Symbol	Absolute Maximum Rating	Unit					
	Nch open-drain output product		Vss - 0.3 to Vss + 28.0	V					
Power supply voltage	Nch driver + built-in pull-up resistor (1.2 kΩ typ.) product	Vdd	$V_{\text{SS}} - 0.3$ to $V_{\text{SS}} + 9.0$	V					
Power supply current	ower supply current		±10 m						
Output current		Іоит	±10	mA					
	Nch open-drain output product		$V_{\text{SS}}-0.3$ to $V_{\text{SS}}+28.0$	V					
Output voltage	Nch driver + built-in pull-up resistor (1.2 k Ω typ.) product	Vout	$V_{\text{SS}} - 0.3$ to $V_{\text{DD}} + 0.3$	V					
Operation ambient tem	perature	T _{opr}	-40 to +125	°C					
Storage temperature		T _{stg}	-40 to +150	°C					

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

Table 7

■ Thermal Resistance Value

Item	Symbol	Condition		Min.	Тур.	Max.	Unit
			Board A	—	225	-	°C/W
			Board B	—	190	-	°C/W
		TSOT-23-3S	Board C	_	-	-	°C/W
	Αιθ		Board D	—		-	°C/W
Junction-to-ambient thermal resistance*1			Board E	—		-	°C/W
Junction-to-ambient thermal resistance			Board A	—	180	-	°C/W
			Board B	—	128	-	°C/W
		HSNT-6(2025)	Board C	—	43	-	°C/W
			Board D	—	44	-	°C/W
			Board E	_	36	-	°C/W

*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "■ **Power Dissipation**" and "**Test Board**" for details.

Electrical Characteristics

1. Nch open-drain output product

Table 8

		(Ta = +25°C, V _{DI}	o = 12.0 V, Vs	s = 0 V ur	nless othe	erwise sp	pecified
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circui
Power supply voltage	V _{DD}	_	2.7	12.0	26.0	V	-
Current consumption	I _{DD}	_	_	4.0	4.5	mA	1
Low level output voltage	Vol	Ιουτ = 5 mA, Vουτ = "L"	-	-	0.4	V	2
Leakage current	ILEAK	V _{OUT} = "H"	-	-	1.0	μA	3
Output limit current	Іом	V _{OUT} = 12.0 V	11	-	35	mA	3
Output delay time ^{*1}	tD	_	-	8	16	μs	-
Chopping frequency*1	fc	_	250	500	_	kHz	-
Start up time*1	t PON	_	-	25	40	μs	4
Output rise time*1	t _R	C = 20 pF, R = 820 Ω	-	_	1.0	μs	5
Output fall time*1	t⊧	C = 20 pF, R = 820 Ω	-	_	1.0	μs	5

***1.** This item is guaranteed by design.

2. Nch driver + built-in pull-up resistor (1.2 k Ω typ.) product

Table 9

(Ta = +25°C, V_{DD} = 5.0 V, V_{SS} = 0 V unless otherwise specified)

Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Power supply voltage	Vdd	_	2.7	5.0	5.5	V	-
Current consumption	IDD	V _{OUT} = "H"	_	4.0	4.5	mA	1
Low level output voltage	Vol	Ιουτ = 0 mA, Vουτ = "L"	-	-	0.4	V	2
High level output voltage	Voh	I _{OUT} = 0 mA, V _{OUT} = "H"	$V_{\text{DD}} \times 0.9$	-	-	V	2
Output limit current	Іом	$V_{DD} = V_{OUT} = 5.0 V$	11	_	35	mA	3
Output delay time*1	tD	_	_	8	16	μs	_
Chopping frequency*1	fc	_	250	500	-	kHz	_
Start up time*1	t _{PON}	_	-	25	40	μs	4
Output rise time*1	t _R	C = 20 pF	_	I	1.0	μs	5
Output fall time*1	t⊨	C = 20 pF	_	_	1.0	μs	5
Pull-up resistor	R∟	_	0.9	1.2	1.5	kΩ	_

*1. This item is guaranteed by design.

125°C OPERATION, HIGH-WITHSTAND VOLTAGE, HIGH-SPEED, BIPOLAR HALL EFFECT LATCH IC S-576B B Series Rev. 1.4_00

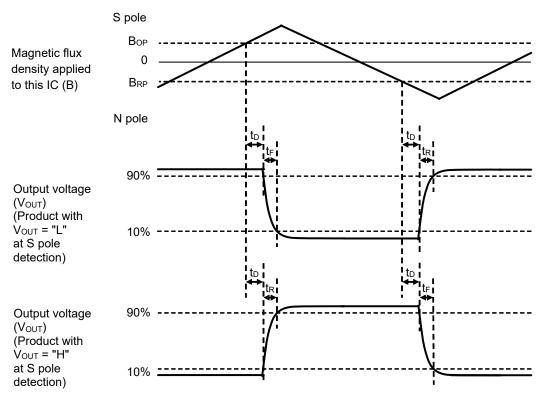


Figure 5 Operation Timing

Magnetic Characteristics

1. TSOT-23-3S

1. 1 Product with $B_{OP} = 0.5 \text{ mT typ.}$

Table 10

(Ta = +25°C, V _{DD} = 5.0 V, V _{SS} = 0 V unless otherwise specifie										
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit		
Operation point*1	S pole	BOP	-	-0.5	0.5	1.5	mT	4		
Release point*2	N pole	BRP	-	-1.5	-0.5	0.5	mT	4		
Hysteresis width*3		BHYS	B _{HYS} = B _{OP} – B _{RP}	-	1.0	-	mT	4		

1. 2 Product with $B_{OP} = 2.2 \text{ mT typ.}$

Table 11

$(Ta = +25^{\circ}C, V_{DD} = 5.0 \text{ V}, V_{SS} = 0 \text{ V}$ unless otherwise specific									
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit	
Operation point*1	S pole	BOP	_	1.2	2.2	3.2	mT	4	
Release point*2	N pole	B _{RP}	_	-3.2	-2.2	-1.2	mT	4	
Hysteresis width*3		B _{HYS}	B _{HYS} = B _{OP} - B _{RP}	-	4.4	-	mT	4	

1. 3 Product with $B_{OP} = 3.0 \text{ mT typ.}$

Table 12

(Ta = +25°C, V_{DD} = 5.0 V, V_{SS} = 0 V unless otherwise specified)

ltem		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	2.0	3.0	4.0	mT	4
Release point*2	N pole	B _{RP}	-	-4.0	-3.0	-2.0	mT	4
Hysteresis width*3		B _{HYS}	B _{HYS} = B _{OP} – B _{RP}	_	6.0	_	mT	4

1. 4 Product with $B_{OP} = 6.0 \text{ mT}$ typ.

Table 13

			(Ta = +25	°C, V _{DD} = {	5.0 V, V _{SS} :	= 0 V unles	ss otherv	vise specified)
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	4.0	6.0	8.0	mT	4
Release point* ²	N pole	B _{RP}	-	-8.0	-6.0	-4.0	mT	4
Hysteresis width*3		B _{HYS}	B _{HYS} = B _{OP} – B _{RP}	-	12.0	-	mT	4

1. 5 Product with $B_{OP} = 10.0 \text{ mT typ.}$

Table 14

			(Ta = +25	°C, V _{DD} = {	5.0 V, Vss	= 0 V unles	ss otherv	vise specified)
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	7.2	10.0	12.6	mT	4
Release point*2	N pole	B _{RP}	-	-12.6	-10.0	-7.2	mT	4
Hysteresis width ^{*3}		BHYS	$B_{HYS} = B_{OP} - B_{RP}$	_	20.0	-	mT	4

ABLIC Inc.

2. HSNT-6(2025)

2. 1 Product with $B_{OP} = 0.5 \text{ mT typ.}$

Table 15

	$(Ta = +25^{\circ}C, V_{DD} = 5.0 V, V_{SS} = 0 V unless otherwise specified)$							
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	-1.1	0.5	2.1	mT	4
Release point*2	N pole	BRP	-	-2.1	-0.5	1.1	mT	4
Hysteresis width*3		BHYS	B _{HYS} = B _{OP} - B _{RP}	_	1.0	-	mT	4

2. 2 Product with $B_{OP} = 2.2 \text{ mT typ.}$

Table 16

			(Ta = +25	°C, V _{DD} = {	5.0 V, Vss	= 0 V unles	ss otherv	vise specified)
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	1.1	2.2	4.2	mT	4
Release point*2	N pole	B _{RP}	_	-4.2	-2.2	-1.1	mT	4
Hysteresis width*3		BHYS	B _{HYS} = B _{OP} - B _{RP}	-	4.4	-	mT	4

2. 3 Product with $B_{OP} = 3.0 \text{ mT typ.}$

Table 17

			(Ta = +25	°C, V _{DD} = {	5.0 V, Vss	= 0 V unles	ss otherv	vise specified)
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	1.0	3.0	5.0	mT	4
Release point*2	N pole	BRP	_	-5.0	-3.0	-1.0	mT	4
Hysteresis width*3		BHYS	B _{HYS} = B _{OP} - B _{RP}	-	6.0	-	mT	4

2. 4 Product with $B_{OP} = 6.0 \text{ mT typ.}$

Table 18

		(Ta = +25°C, V _{DD} = 5.0 V, V _{SS} = 0 V unless otherwise specified)						
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	3.6	6.0	8.4	mT	4
Release point*2	N pole	B _{RP}	_	-8.4	-6.0	-3.6	mT	4
Hysteresis width*3		BHYS	B _{HYS} = B _{OP} - B _{RP}	_	12.0	-	mT	4

2. 5 Product with $B_{OP} = 10.0 \text{ mT}$ typ.

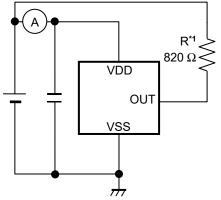
Table 19

			(Ta = +25	°C, V _{DD} = 8	5.0 V, Vss	= 0 V unles	ss otherv	vise specified)
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	_	7.4	10.0	13.0	mT	4
Release point*2	N pole	B _{RP}	-	-13.0	-10.0	-7.4	mT	4
Hysteresis width*3		B _{HYS}	BHYS = BOP - BRP	_	20.0	-	mT	4

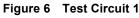
- *1. BOP: Operation point BOP is the value of magnetic flux density when the output voltage (VOUT) changes after the magnetic flux density applied to this IC by the magnet (S pole) is increased (by moving the magnet closer).
 VOUT retains the status until a magnetic flux density of the N pole higher than BRP is applied.
- *2. B_{RP}: Release point B_{RP} is the value of magnetic flux density when the output voltage (V_{OUT}) changes after the magnetic flux density applied to this IC by the magnet (N pole) is increased (by moving the magnet closer).
 V_{OUT} retains the status until a magnetic flux density of the S pole higher than B_{OP} is applied.
- *3. B_{HYS}: Hysteresis width B_{HYS} is the difference of magnetic flux density between B_{OP} and B_{RP}.

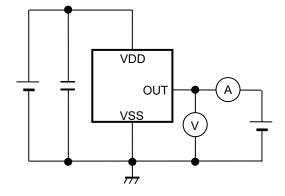
Remark The unit of magnetic density mT can be converted by using the formula 1 mT = 10 Gauss.

Test Circuits

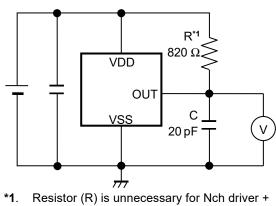


*1. Resistor (R) is unnecessary for Nch driver + built-in pull-up resistor product.



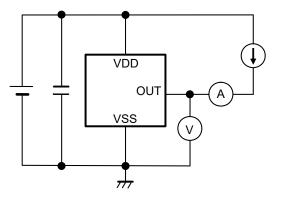




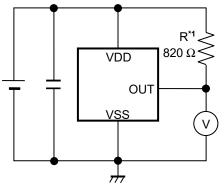


built-in pull-up resistor product.





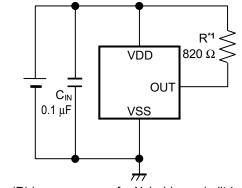




*1. Resistor (R) is unnecessary for Nch driver + built-in pull-up resistor product.

Figure 9 Test Circuit 4

Standard Circuit



*1. Resistor (R) is unnecessary for Nch driver + built-in pull-up resistor product.

Figure 11

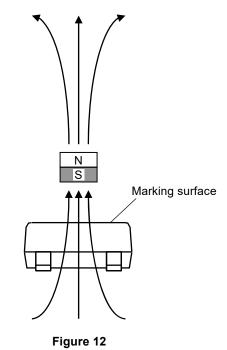
Caution The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constants.

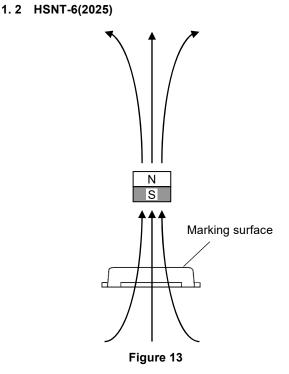
Operation

1. Direction of applied magnetic flux

This IC detects the magnetic flux density which is perpendicular to the package marking surface. A magnetic field is defined as positive when marking side of the package is the S pole, and negative when it is the N pole. **Figure 12** and **Figure 13** show polarity in a magnetic field and direction in which magnetic flux is being applied.

1.1 TSOT-23-3S





2. Position of Hall sensor

Figure 14 and Figure 15 show the position of Hall sensor.

The center of this Hall sensor is located in the area indicated by a circle, which is in the center of a package as described below.

The following also shows the distance (typ. value) between the marking surface and the chip surface of a package.

2.1 TSOT-23-3S

2.2 HSNT-6(2025)

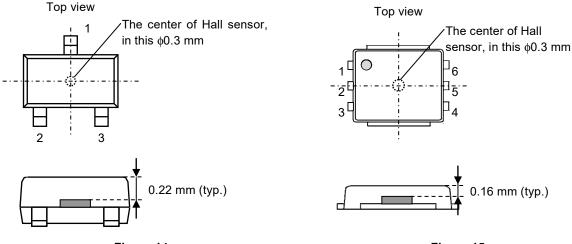


Figure 14

Figure 15

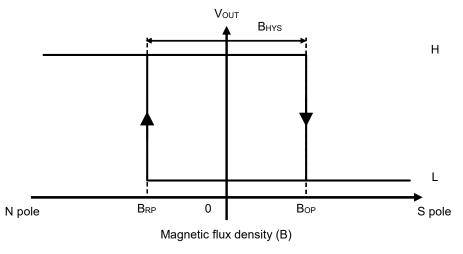
ABLIC Inc.

3. Basic operation

This IC changes the output voltage (V_{OUT}) according to the level of the magnetic flux density (N pole or S pole) and a polarity change applied by a magnet.

3. 1 Product with V_{OUT} = "L" at S pole detection

When the magnetic flux density of the S pole perpendicular to the marking surface exceeds the operation point (B_{OP}) (B > B_{OP}) after the S pole of a magnet is moved closer to the marking surface of this IC, V_{OUT} changes from "H" to "L". When the N pole of a magnet is moved closer to the marking surface of this IC and the magnetic flux density of the N pole is higher than the release point (B_{RP}) (B < B_{RP}), V_{OUT} changes from "L" to "H". In case of B_{RP} < B < B_{OP}, V_{OUT} retains the level. **Figure 16** shows the relationship between the magnetic flux density and V_{OUT}.





3. 2 Product with Vout = "H" at S pole detection

When the magnetic flux density of the S pole perpendicular to the marking surface exceeds B_{OP} (B > B_{OP}) after the S pole of a magnet is moved closer to the marking surface of this IC, V_{OUT} changes from "L" to "H". When the N pole of a magnet is moved closer to the marking surface of this IC and the magnetic flux density of the N pole is higher than B_{RP} (B < B_{RP}), V_{OUT} changes from "H" to "L". In case of $B_{RP} < B < B_{OP}$, V_{OUT} retains the level. **Figure 17** shows the relationship between the magnetic flux density and V_{OUT} .

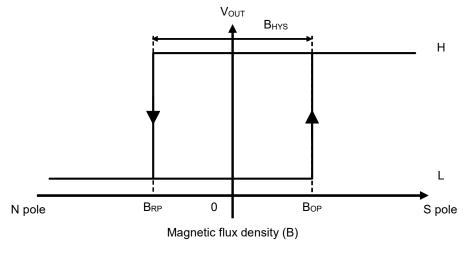


Figure 17

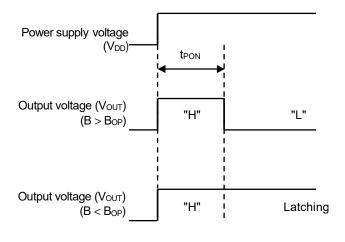
4. Power-on operation

The output voltage (V_{OUT}) of this IC immediately after power-on is "H". After the start up time (t_{PON}) is passed, the IC changes V_{OUT} according to the level of the magnetic flux density (N pole or S pole) and a polarity change applied by a magnet.

4. 1 Product with V_{OUT} = "L" at S pole detection

Figure 18 shows the timing chart at power-on for product with $V_{OUT} = "L"$ at S pole detection. The initial output voltage at rising of power supply voltage (V_{DD}) is "H".

In case of B > B_{OP} at the time when t_{PON} is passed after rising of V_{DD}, V_{OUT} changes from "H" to "L". In case of B < B_{OP} at the time when t_{PON} is passed after rising of V_{DD}, V_{OUT} retains "H".





4. 2 Product with VOUT = "H" at S pole detection

Figure 19 shows the timing chart at power-on for product with $V_{OUT} = "H"$ at S pole detection. The initial output voltage at rising of power supply voltage (V_{DD}) is "H". In case of B > B_{RP} at the time when t_{PON} is passed after rising of V_{DD}, V_{OUT} retains "H". In case of B < B_{RP} at the time when t_{PON} is passed after rising of V_{DD}, V_{OUT} changes from "H" to "L".

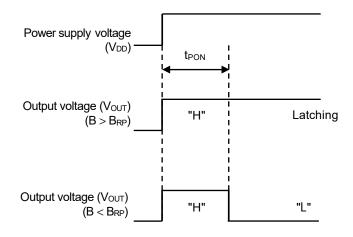


Figure 19

ABLIC Inc.

Precautions

- If the impedance of the power supply is high, the IC may malfunction due to a supply voltage drop caused by feed-through current. Take care with the pattern wiring to ensure that the impedance of the power supply is low.
- Note that the IC may malfunction if the power supply voltage rapidly changes. When the IC is used under the environment where the power supply voltage rapidly changes, it is recommended to judge the output voltage of the IC by reading it multiple times.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- Although this IC has a built-in output current limit circuit, it may suffer physical damage such as product deterioration under the environment where the absolute maximum ratings are exceeded.
- The application conditions for the power supply voltage, the pull-up voltage, and the pull-up resistor should not exceed the power dissipation.
- Large stress on this IC may affect the magnetic characteristics. Avoid large stress which is caused by the handling during or after mounting the IC on a board.
- Since the package heat radiation differs according to the conditions of the application, perform thorough evaluation with actual applications to confirm no problems occur.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

1. 1. 2

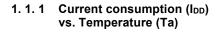
Current consumption (IDD)

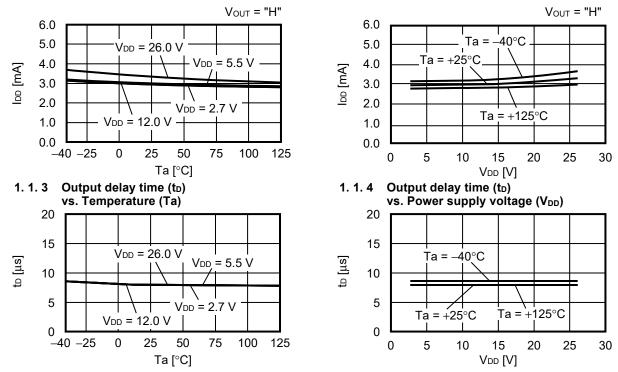
vs. Power supply voltage (VDD)

■ Characteristics (Typical Data)

1. Electrical Characteristics

1.1 S-576BxxxB

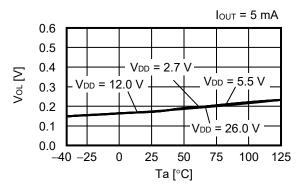




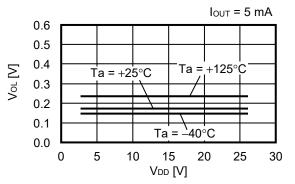
Caution $V_{DD} = 2.7$ V to 5.5 V when output form is Nch driver + built-in pull-up resistor (1.2 k Ω typ.). Comply with power supply voltage range and do not exceed absolute maximum ratings.

1.2 S-576BNxxB

1. 2. 1 Low level output voltage (Vo∟) vs. Temperature (Ta)

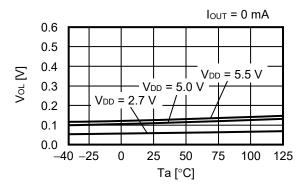


1.2.2 Low level output voltage (V_{OL}) vs. Power supply voltage (V_{DD})

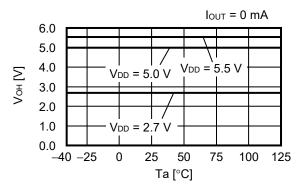


1.3 S-576B1xxB

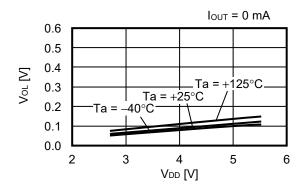
1.3.1 Low level output voltage (V_{OL}) vs. Temperature (Ta)



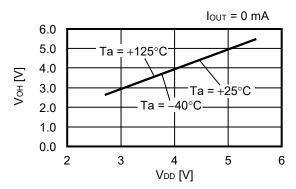
1.3.3 High level output voltage (V_{OH}) vs. Temperature (Ta)



1.3.2 Low level output voltage (V_{OL}) vs. Power supply voltage (V_{DD})



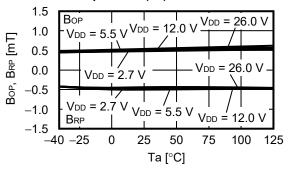
1.3.4 High level output voltage (V_{OH}) vs. Power supply voltage (V_{DD})



2 Magnetic Characteristics

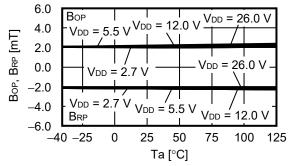
2.1 S-576Bxx9B-L3T2U

2. 1. 1 Operation point, release point (B_{OP}, B_{RP}) vs. Temperature (Ta)



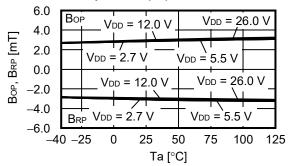
2.2 S-576Bxx8B-L3T2U

2. 2. 1 Operation point, release point (Bop, BRP) vs. Temperature (Ta)

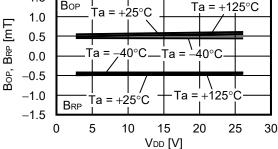


2.3 S-576Bxx1B-L3T2U

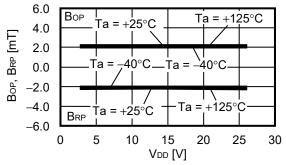
2. 3. 1 Operation point, release point (Bop, BRP) vs. Temperature (Ta)



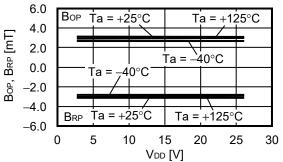
2. 1. 2 Operation point, release point (B_{OP}, B_{RP}) vs. Power supply voltage (V_{DD})



2. 2. 2 Operation point, release point (BoP, BRP) vs. Power supply voltage (V_{DD})



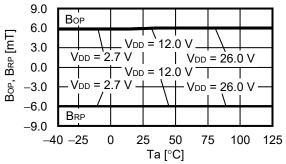
2. 3. 2 Operation point, release point (B_{OP}, B_{RP}) vs. Power supply voltage (V_{DD})



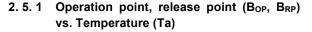
Caution $V_{DD} = 2.7$ V to 5.5 V when output form is Nch driver + built-in pull-up resistor (1.2 k Ω typ.). Comply with power supply voltage range and do not exceed absolute maximum ratings.

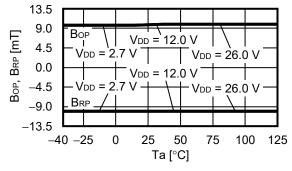
2.4 S-576Bxx3B-L3T2U

2. 4. 1 Operation point, release point (Bop, BRP) vs. Temperature (Ta)

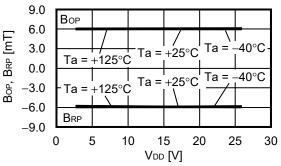


2.5 S-576Bxx4B-L3T2U

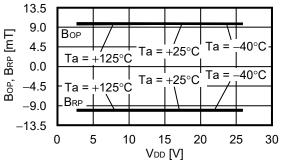




2. 4. 2 Operation point, release point (B_{OP}, B_{RP}) vs. Power supply voltage (V_{DD})

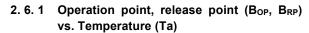


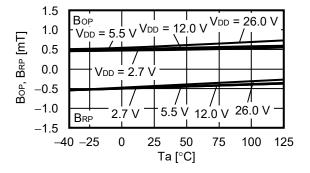
2. 5. 2 Operation point, release point (B_{OP}, B_{RP}) vs. Power supply voltage (V_{DD})



Caution $V_{DD} = 2.7$ V to 5.5 V when output form is Nch driver + built-in pull-up resistor (1.2 k Ω typ.). Comply with power supply voltage range and do not exceed absolute maximum ratings.

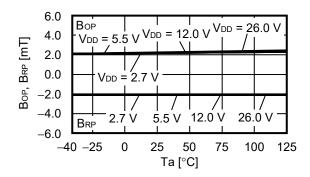
2.6 S-576Bxx9B-A6T8U





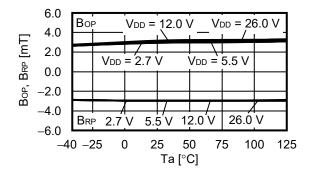
2.7 S-576Bxx8B-A6T8U

2. 7. 1 Operation point, release point (Bop, BRP) vs. Temperature (Ta)

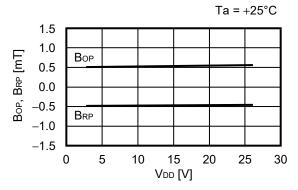


2.8 S-576Bxx1B-A6T8U

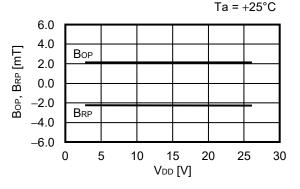
2. 8. 1 Operation point, release point (B_{OP}, B_{RP}) vs. Temperature (Ta)



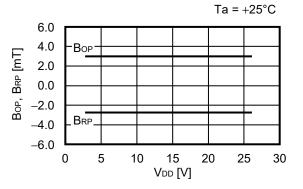
2. 6. 2 Operation point, release point (B_{OP}, B_{RP}) vs. Power supply voltage (V_{DD})



2.7.2 Operation point, release point (Bop, BRP) vs. Power supply voltage (V_{DD})



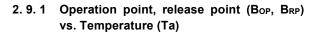
2. 8. 2 Operation point, release point (Bop, BRP) vs. Power supply voltage (VDD)

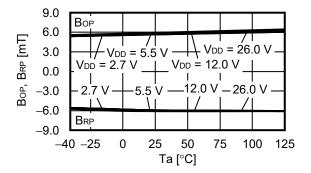


Caution $V_{DD} = 2.7$ V to 5.5 V when output form is Nch driver + built-in pull-up resistor (1.2 k Ω typ.). Comply with power supply voltage range and do not exceed absolute maximum ratings.

ABLIC Inc.

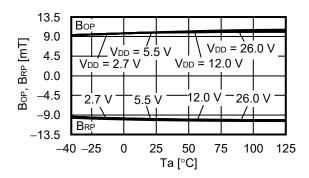
2.9 S-576Bxx3B-A6T8U



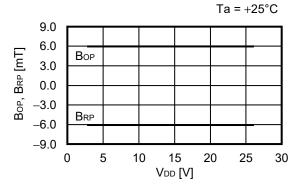


2.10 S-576Bxx4B-A6T8U

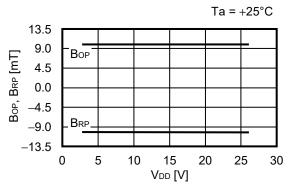
2. 10. 1 Operation point, release point (B_{OP}, B_{RP}) vs. Temperature (Ta)



2. 9. 2 Operation point, release point (B_{OP}, B_{RP}) vs. Power supply voltage (V_{DD})



2.10.2 Operation point, release point (Bop, BRP) vs. Power supply voltage (VDD)

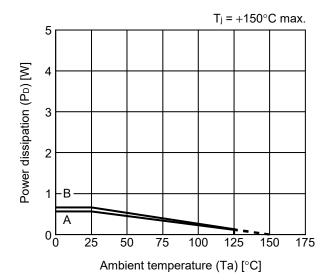


Caution $V_{DD} = 2.7$ V to 5.5 V when output form is Nch driver + built-in pull-up resistor (1.2 k Ω typ.). Comply with power supply voltage range and do not exceed absolute maximum ratings.

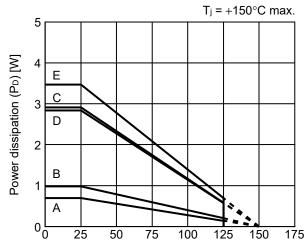
Power Dissipation

TSOT-23-3S

HSNT-6(2025)



Board	Power Dissipation (P _D)
А	0.56 W
В	0.66 W
С	_
D	_
E	_



Ambient temperature (Ta) [°C]

Board	Power Dissipation (P _D)
А	0.69 W
В	0.98 W
С	2.91 W
D	2.84 W
E	3.47 W

TSOT-23-3S Test Board

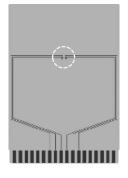
IC Mount Area

(1) Board A



Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil la	ayer	2
	1	Land pattern and wiring for testing: t0.070
Copper foil layer [mm]	2	-
	3	-
	4	74.2 x 74.2 x t0.070
Thermal via		-

(2) Board B



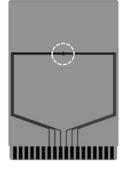
Item		Specification			
Size [mm]		114.3 x 76.2 x t1.6			
Material		FR-4			
Number of copper foil layer		4			
	1	Land pattern and wiring for testing: t0.070			
Coppor foil lovor [mm]	2	74.2 x 74.2 x t0.035			
Copper foil layer [mm]	3	74.2 x 74.2 x t0.035			
	4	74.2 x 74.2 x t0.070			
Thermal via		-			

No. TSOT23x-A-Board-SD-1.0

HSNT-6(2025) Test Board

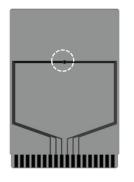
IC Mount Area

(1) Board A



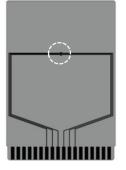
Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		2
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	-
	3	-
	4	74.2 x 74.2 x t0.070
Thermal via		-

(2) Board B



Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

(3) Board C



Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		Number: 4 Diameter: 0.3 mm

≡≣≡

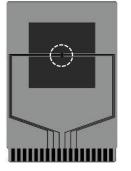
enlarged view

No. HSNT6-B-Board-SD-1.0

HSNT-6(2025) Test Board

) IC Mount Area

(4) Board D

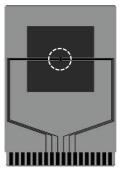


Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Pattern for heat radiation: 2000mm ² t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-



enlarged view

(5) Board E

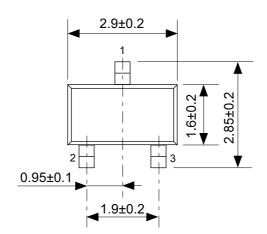


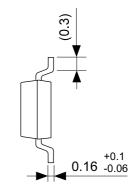
Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Pattern for heat radiation: 2000mm ² t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		Number: 4 Diameter: 0.3 mm

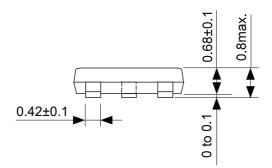


enlarged view

No. HSNT6-B-Board-SD-1.0

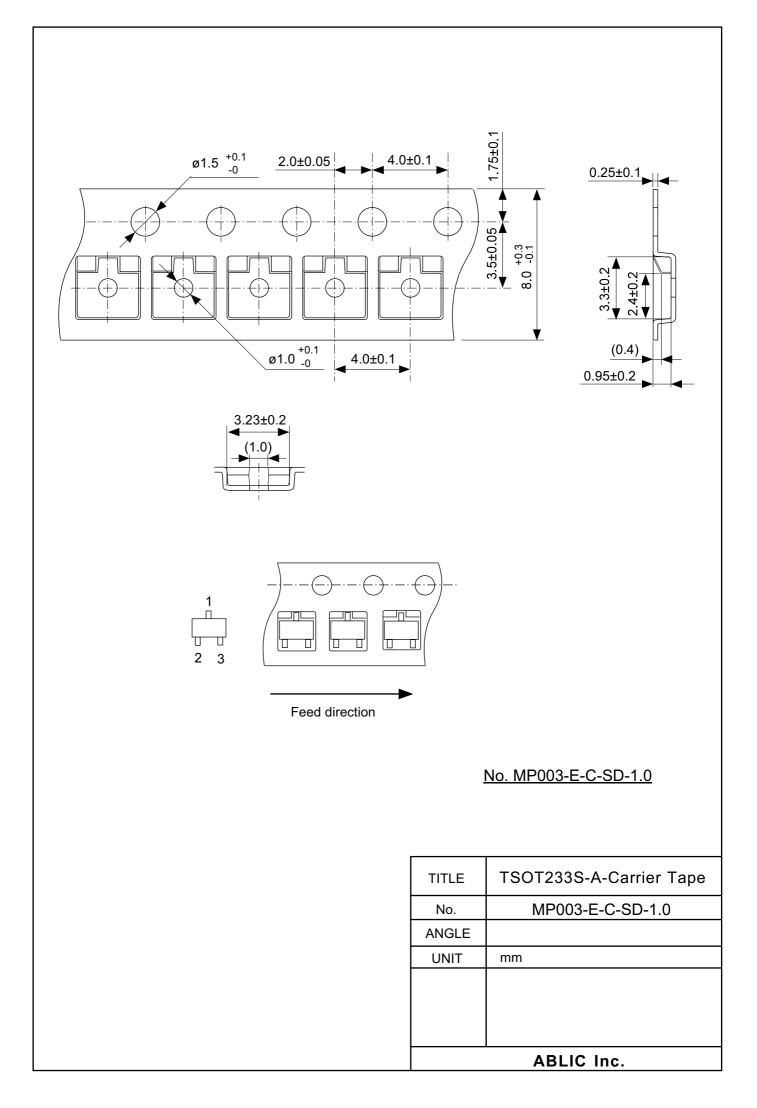


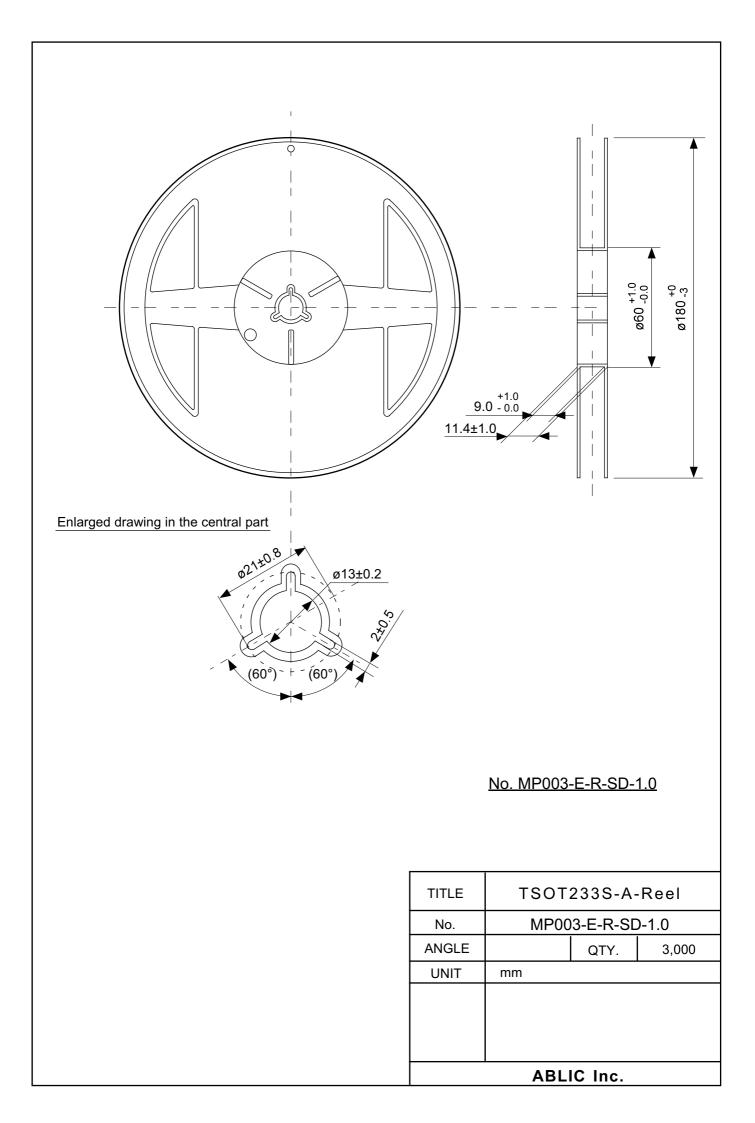


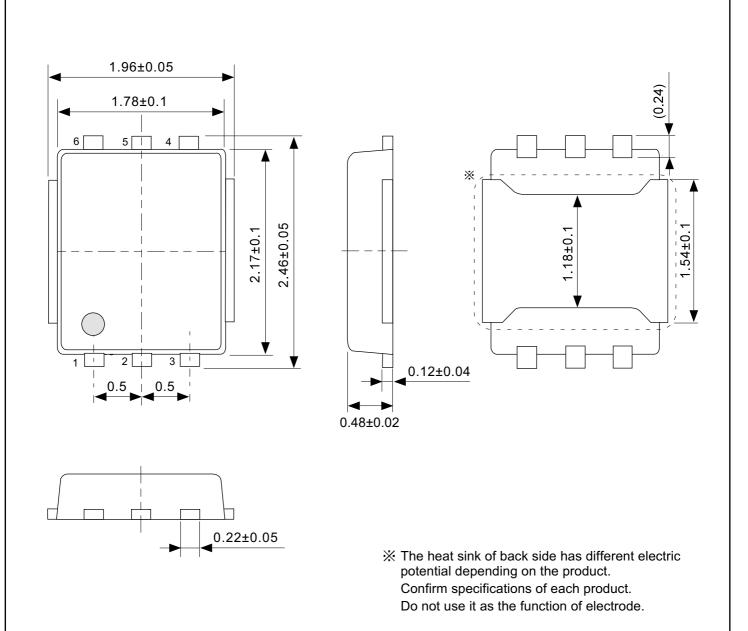


No. MP003-E-P-SD-1.0

TITLE	TSOT233S-A-PKG Dimensions	
No.	MP003-E-P-SD-1.0	
ANGLE	Φ	
UNIT	mm	
ABLIC Inc.		

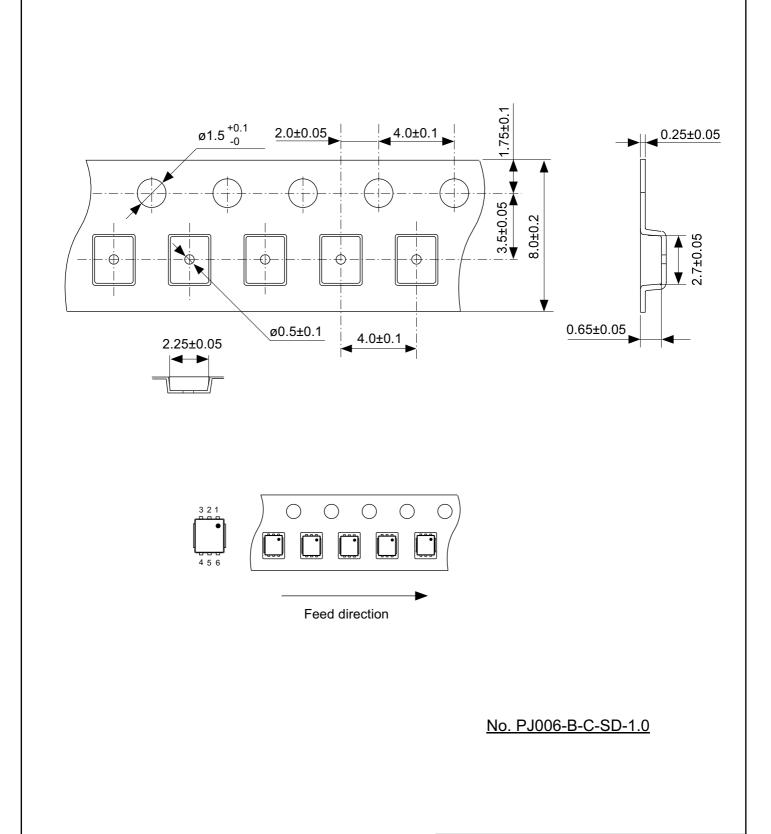




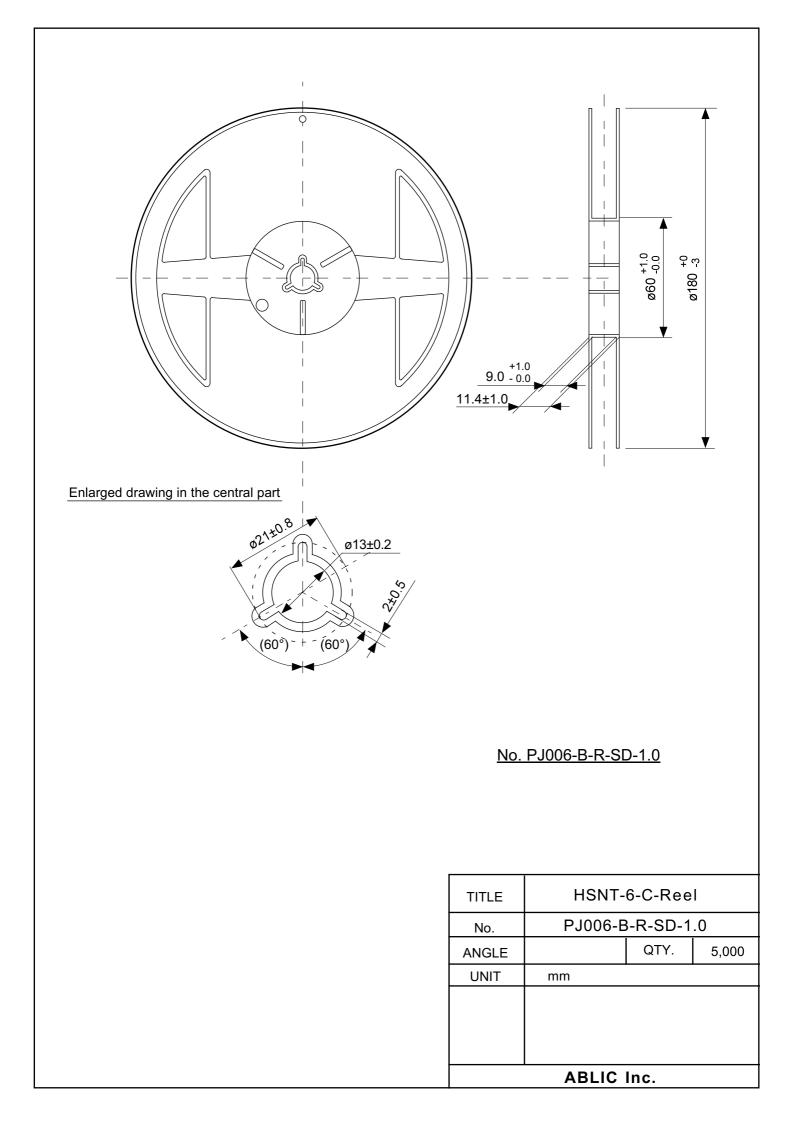


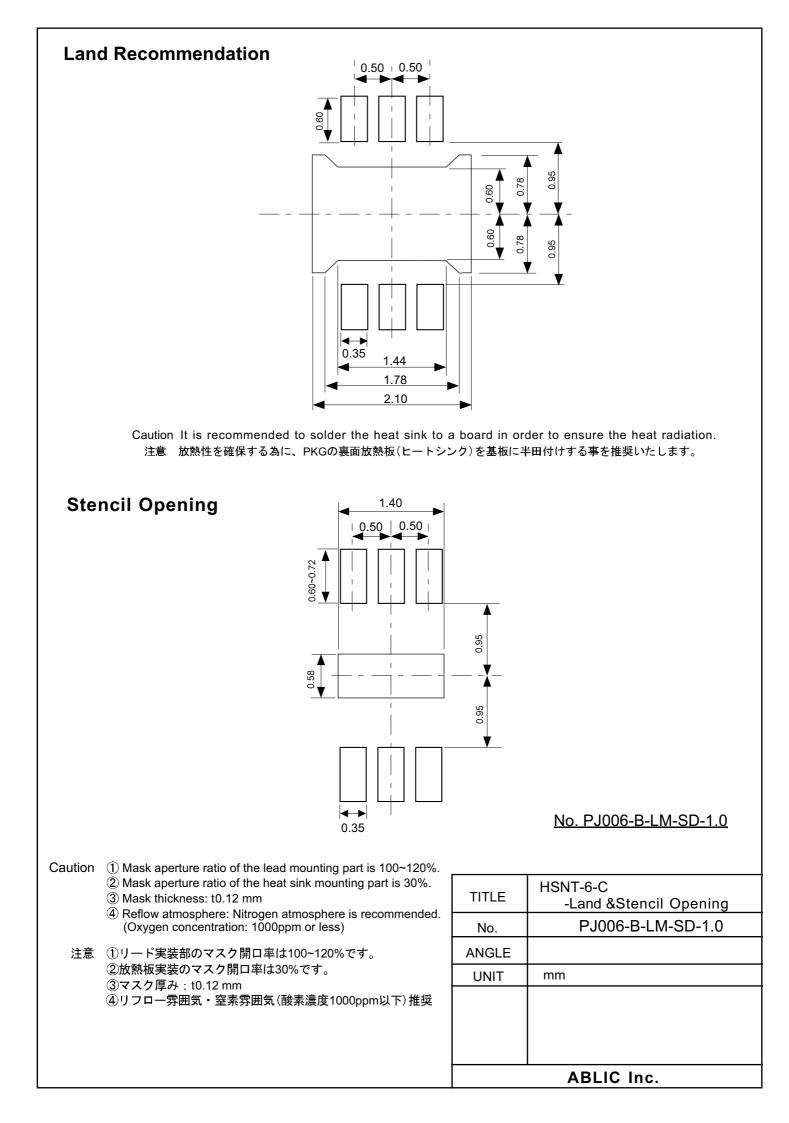
No. PJ006-B-P-SD-1.0

TITLE	HSNT-6-C-PKG Dimensions	
No.	PJ006-B-P-SD-1.0	
ANGLE	$\bigoplus \Box$	
UNIT	mm	
ABLIC Inc.		



TITLE	HSNT-6-C-Carrier Tape	
No.	PJ006-B-C-SD-1.0	
ANGLE		
UNIT	mm	
ABLIC Inc.		





Disclaimers (Handling Precautions)

- 1. All the information described herein (product data, specifications, figures, tables, programs, algorithms and application circuit examples, etc.) is current as of publishing date of this document and is subject to change without notice.
- The circuit examples and the usages described herein are for reference only, and do not guarantee the success of any specific mass-production design.
 ABLIC Inc. is not liable for any losses, damages, claims or demands caused by the reasons other than the products described herein (hereinafter "the products") or infringement of third-party intellectual property right and any other right due to the use of the information described herein.
- 3. ABLIC Inc. is not liable for any losses, damages, claims or demands caused by the incorrect information described herein.
- 4. Be careful to use the products within their ranges described herein. Pay special attention for use to the absolute maximum ratings, operation voltage range and electrical characteristics, etc. ABLIC Inc. is not liable for any losses, damages, claims or demands caused by failures and / or accidents, etc. due to the use of the products outside their specified ranges.
- 5. Before using the products, confirm their applications, and the laws and regulations of the region or country where they are used and verify suitability, safety and other factors for the intended use.
- 6. When exporting the products, comply with the Foreign Exchange and Foreign Trade Act and all other export-related laws, and follow the required procedures.
- 7. The products are strictly prohibited from using, providing or exporting for the purposes of the development of weapons of mass destruction or military use. ABLIC Inc. is not liable for any losses, damages, claims or demands caused by any provision or export to the person or entity who intends to develop, manufacture, use or store nuclear, biological or chemical weapons or missiles, or use any other military purposes.
- 8. The products are not designed to be used as part of any device or equipment that may affect the human body, human life, or assets (such as medical equipment, disaster prevention systems, security systems, combustion control systems, infrastructure control systems, vehicle equipment, traffic systems, in-vehicle equipment, aviation equipment, aerospace equipment, and nuclear-related equipment), excluding when specified for in-vehicle use or other uses by ABLIC, Inc. Do not apply the products to the above listed devices and equipments. ABLIC Inc. is not liable for any losses, damages, claims or demands caused by unauthorized or unspecified use of the products.
- 9. In general, semiconductor products may fail or malfunction with some probability. The user of the products should therefore take responsibility to give thorough consideration to safety design including redundancy, fire spread prevention measures, and malfunction prevention to prevent accidents causing injury or death, fires and social damage, etc. that may ensue from the products' failure or malfunction.

The entire system in which the products are used must be sufficiently evaluated and judged whether the products are allowed to apply for the system on customer's own responsibility.

- 10. The products are not designed to be radiation-proof. The necessary radiation measures should be taken in the product design by the customer depending on the intended use.
- 11. The products do not affect human health under normal use. However, they contain chemical substances and heavy metals and should therefore not be put in the mouth. The fracture surfaces of wafers and chips may be sharp. Be careful when handling these with the bare hands to prevent injuries, etc.
- 12. When disposing of the products, comply with the laws and ordinances of the country or region where they are used.
- 13. The information described herein contains copyright information and know-how of ABLIC Inc. The information described herein does not convey any license under any intellectual property rights or any other rights belonging to ABLIC Inc. or a third party. Reproduction or copying of the information from this document or any part of this document described herein for the purpose of disclosing it to a third-party is strictly prohibited without the express permission of ABLIC Inc.
- 14. For more details on the information described herein or any other questions, please contact ABLIC Inc.'s sales representative.
- 15. This Disclaimers have been delivered in a text using the Japanese language, which text, despite any translations into the English language and the Chinese language, shall be controlling.



2.4-2019.07